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Tx 270318 ANSUSE I -**FAST RECOVERY DIODE****ARF612**

Repetitive voltage up to

1500 V

Mean forward current

425 A

Surge current

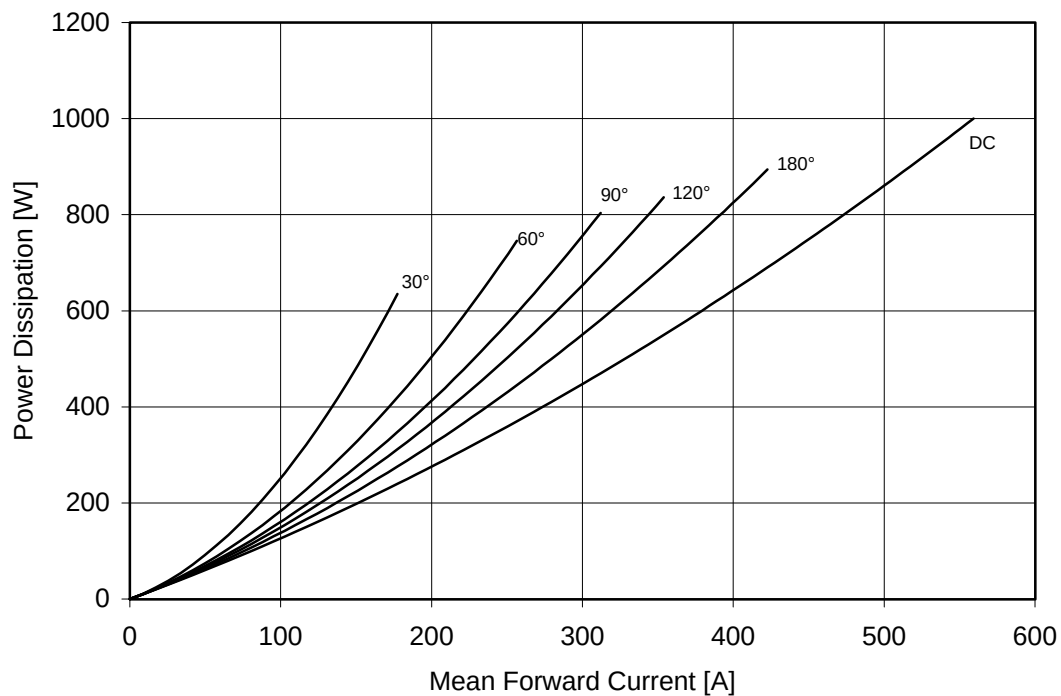
4 kA**FINAL SPECIFICATION**

feb 97 - ISSUE : 03

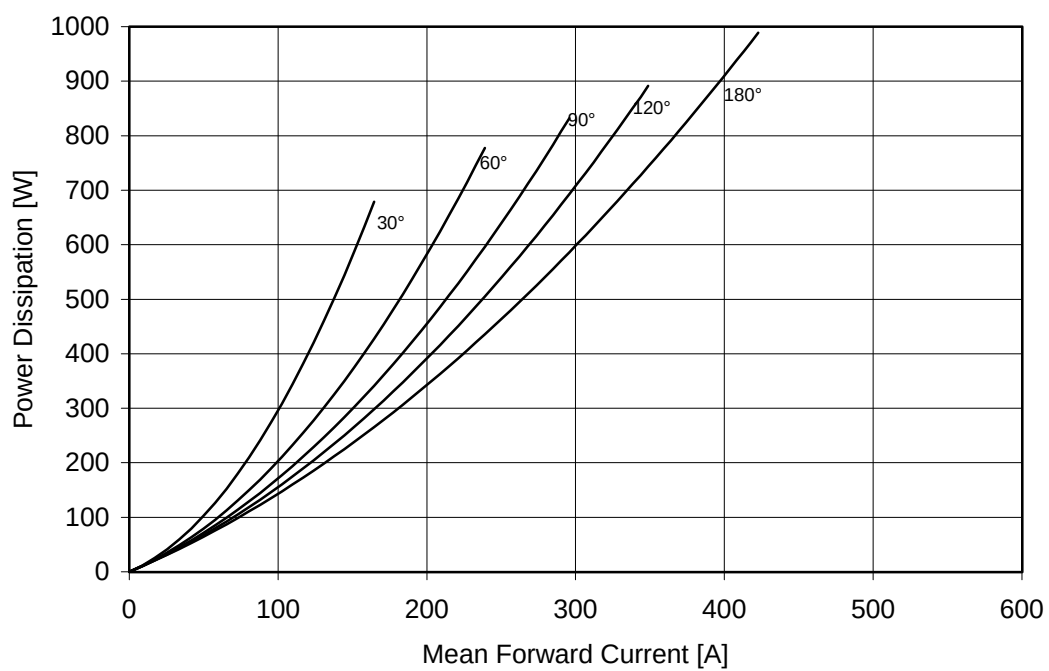
Symbol	Characteristic	Conditions	T _j [°C]	Value	Unit
BLOCKING					
V _{RRM}	Repetitive peak reverse voltage		150	1500	V
V _{RSM}	Non-repetitive peak reverse voltage		150	1600	V
I _{RRM}	Repetitive peak reverse current	V=VRRM	150	40	mA
CONDUCTING					
I _{F(AV)}	Mean forward current	180° sin ,50 Hz, Th=55°C, double side cooled		425	A
I _{F(AV)}	Mean forward current	180° square,50 Hz,Th=55°C,double side cooled		425	A
I _{FSM}	Surge forward current	Sine wave, 10 ms	150	3.8	kA
I ² t	I ² t	reapplied reverse voltage up to 50% VRSM		72 x1E3	A²s
V _{FM}	Forward voltage	Forward current 1000 A	25	2.6	V
V _{F(TO)}	Threshold voltage		150	1.15	V
r _F	Forward slope resistance		150	1.141	mohm
SWITCHING					
t _{rr}	Reverse recovery time	I _F = 200 A di/dt= 50 A/μs VR = 100 V	150	4	μs
Q _{rr}	Reverse recovery charge			210	μC
I _{rr}	Peak reverse recovery current			105	A
s	Softness (s-factor), min			0.4	
V _{FR}	Peak forward recovery	di/dt= 400 A/μs	150	9	V
MOUNTING					
R _{th(j-h)}	Thermal impedance	Junction to heatsink, double side cooled		95	°C/kW
T _j	Operating junction temperature			-30 / 150	°C
F	Mounting force			4.5 / 5.0	kN
	Mass			55	g
ORDERING INFORMATION : ARF612 S 15 standard specification ☐ ☐ VRRM/100					

DISSIPATION CHARACTERISTICS

SQUARE WAVE

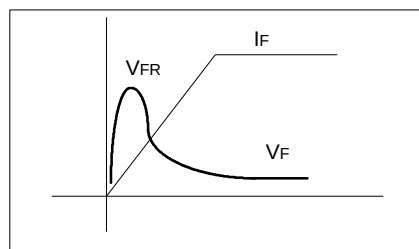
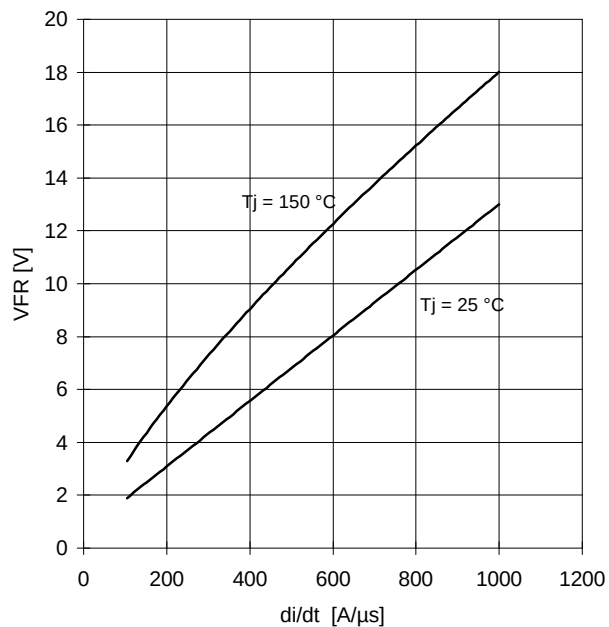


SINE WAVE



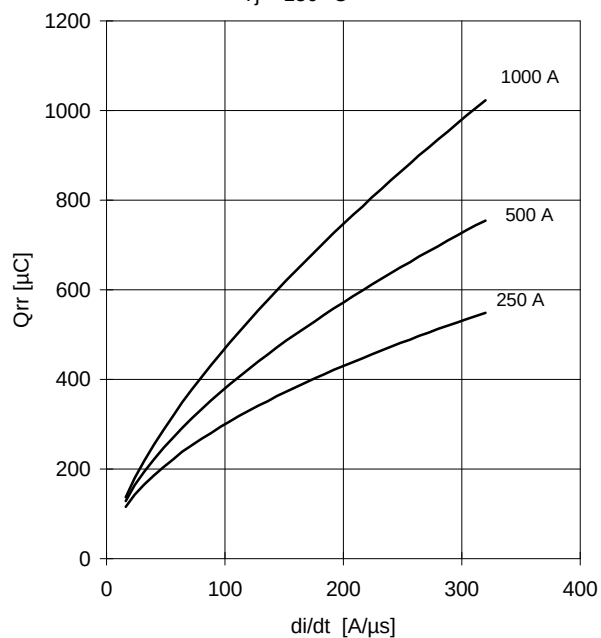
SWITCHING CHARACTERISTICS

FORWARD RECOVERY VOLTAGE



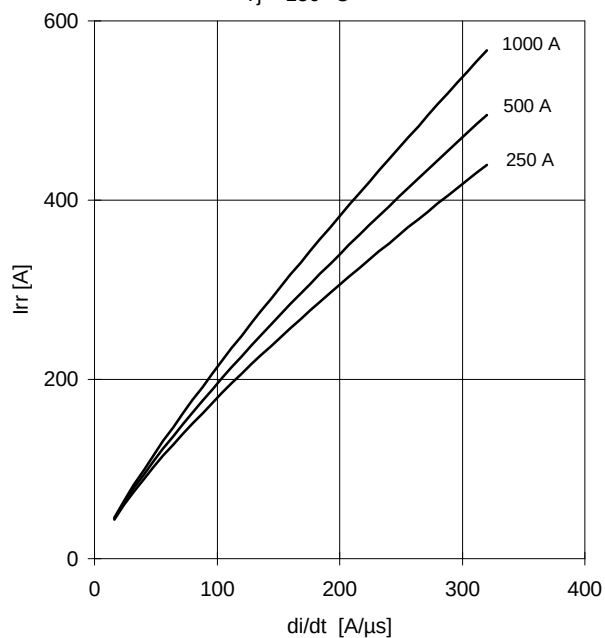
REVERSE RECOVERY CHARGE

$T_j = 150\text{ }^{\circ}\text{C}$



REVERSE RECOVERY CURRENT

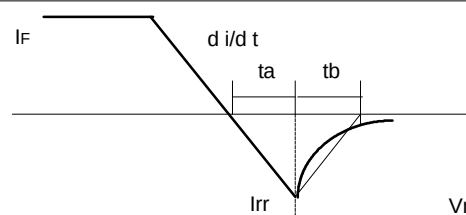
$T_j = 150\text{ }^{\circ}\text{C}$



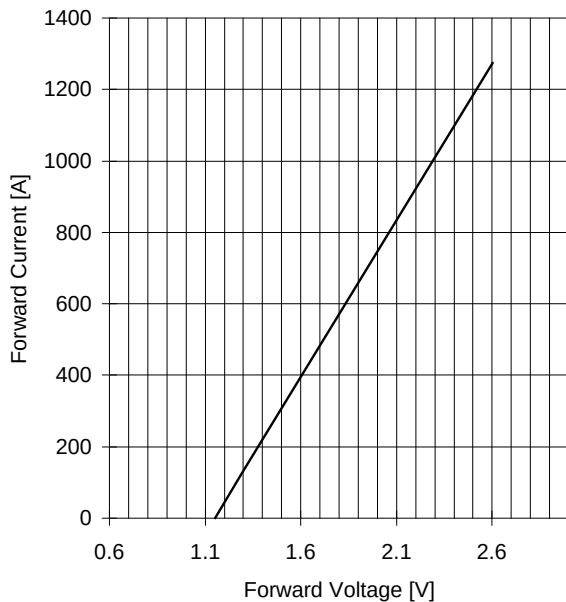
$$t_a = I_{rr} / (di/dt) \quad t_b = t_{rr} - t_a$$

$$\text{Softness (s factor)} \quad s = t_b / t_a$$

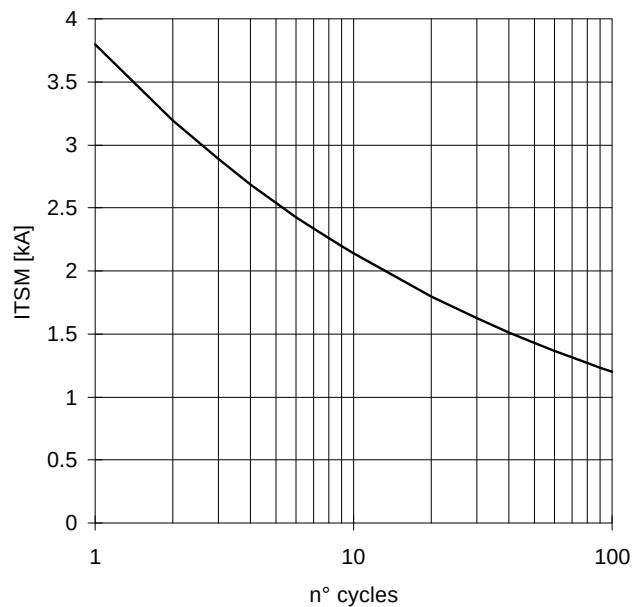
$$\text{Energy dissipation during recovery } E_r = V_r \cdot (Q_{rr} - I_{rr} \cdot t_a / 2)$$



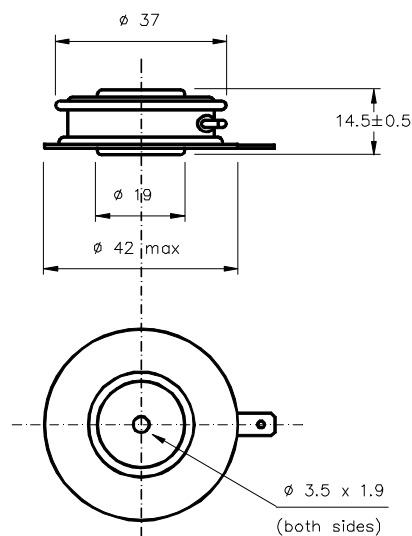
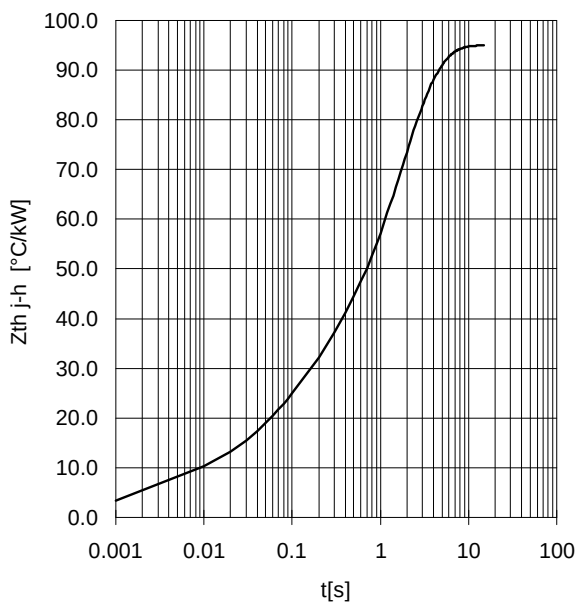
FORWARD CHARACTERISTIC
T_j = 150 °C



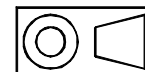
SURGE CHARACTERISTIC
T_j = 150 °C



TRANSIENT THERMAL IMPEDANCE
DOUBLE SIDE COOLED



Dimensions
in mm

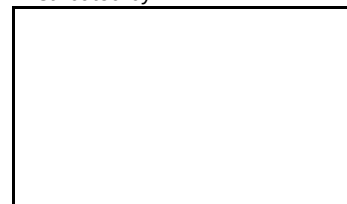


All the characteristics given in this data sheet are guaranteed only with uniform clamping force, cleaned and lubricated heatsink, surfaces with flatness < .03 mm and roughness < 2 μ m.

In the interest of product improvement ANSALDO reserves the right to change any data given in this data sheet at any time without previous notice.

If not stated otherwise the maximum value of ratings (symbols over shaded background) and characteristics is reported.

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